

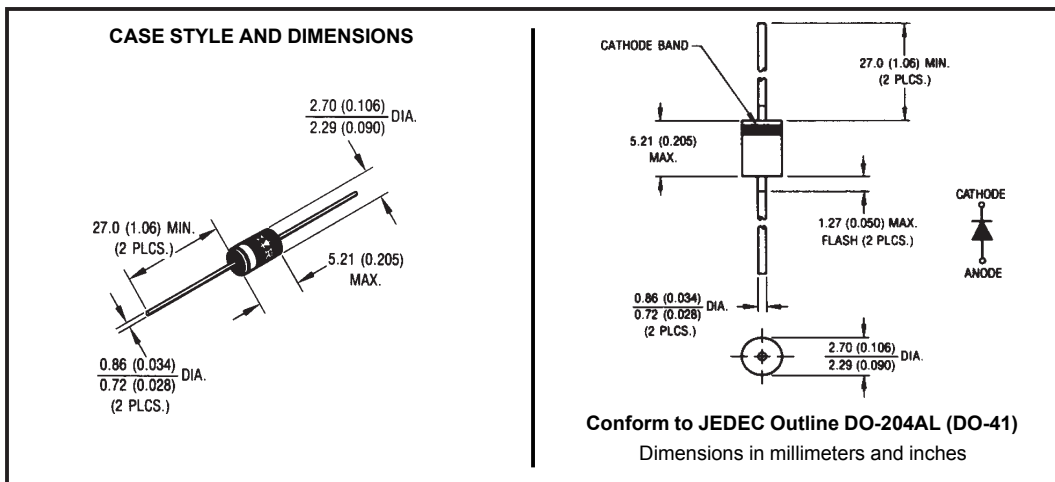
Major Ratings and Characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular waveform	1.0	A
V_{RRM}	20	V
I_{FSM} @tp = 5 μ s sine	240	A
V_F @ 1 Apk, $T_J = 25^\circ\text{C}$	0.45	V
T_J range	-65 to 150	$^\circ\text{C}$

Description/Features

The 1N5817 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Lead-Free plating



Voltage Ratings

Part number	1N5817
V_R Max. DC Reverse Voltage (V)	20
V_{RWM} Max. Working Peak Reverse Voltage (V)	

Absolute Maximum Ratings

Parameters	1N5817	Units	Conditions
$I_{F(AV)}$ Max. Average Forward Current	1.0	A	50% duty cycle @ $T_L = 138^\circ\text{C}$, rectangular wave form
I_{FSM} Max. Peak One Cycle Non-Repetitive Surge Current, @ $T_J = 25^\circ\text{C}$	240	A	5 μs Sine or 3 μs Rect. pulse
	40		10ms Sine or 6ms Rect. pulse

Following any rated load condition and with rated V_{RWM} applied

Electrical Specifications

Parameters	Typ.	Max.	Units	Conditions
V_{FM} Max. Forward Voltage Drop (1)	0.42	0.45	V	@ 1A
	0.50	0.75	V	@ 3A
I_{RM} Max. Reverse Leakage Current (1)	0.012	1.0	mA	$T_J = 25^\circ\text{C}$
	2.0	10	mA	$T_J = 100^\circ\text{C}$
C_T Typical Junction Capacitance	110	-	pF	$V_R = 5V_{DC}$ (test signal range 100kHz to 1Mhz), @ 25°C
L_S Typical Series Inductance	8.0	-	nH	Measured lead to lead 5mm from package body
dv/dt Max. Voltage Rate of Change	-	10000	V/ μs	(Rated V_R)

(1) Pulse Width < 300 μs , Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	1N5817	Units	Conditions
T_J Max. Junction Temperature Range (2)	-65 to 150	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-65 to 150	$^\circ\text{C}$	
R_{thJL} Max. Thermal Resistance Junction to Lead	32	$^\circ\text{C}/\text{W}$	DC operation, Lead length = 1/8 inch.
R_{thJA} Max. Thermal Resistance Junction to Ambient	100	$^\circ\text{C}/\text{W}$	DC operation, without cooling fin
Wt Approximate Weight	0.33(0.012)	gr (oz)	
Case Style	DO-204AL(DO-41)		

(2) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

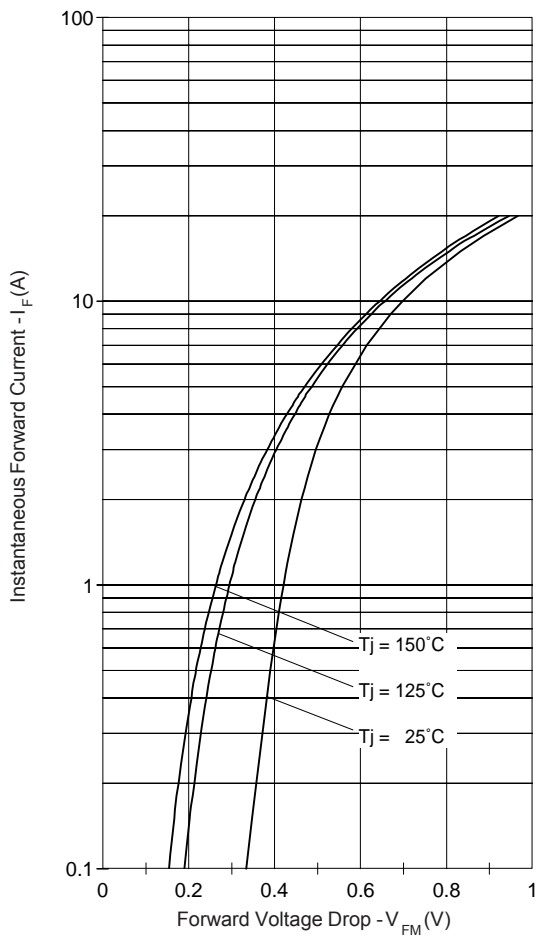


Fig. 1 - Typical Forward Voltage Drop Characteristics

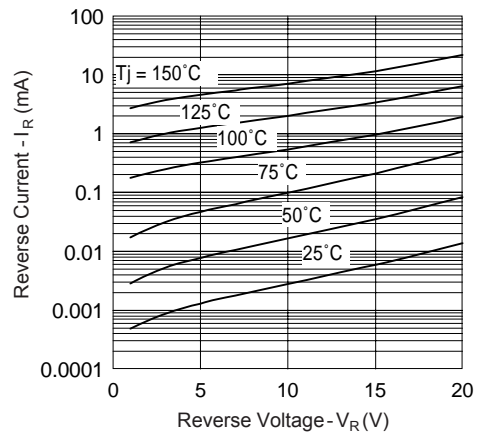


Fig. 2 - Typical Peak Reverse Current Vs. Reverse Voltage

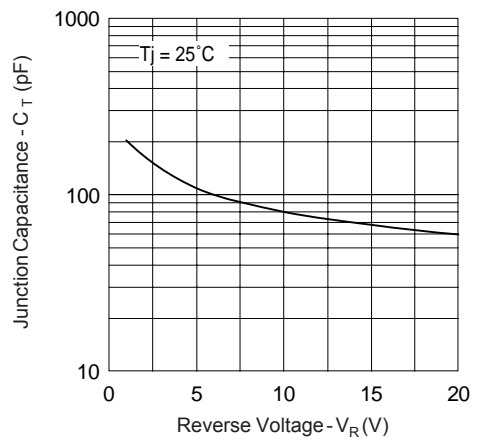


Fig. 3 - Typical Junction Capacitance Vs. Reverse Voltage

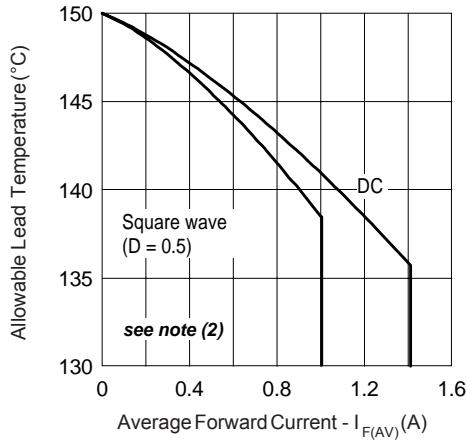


Fig. 4 - Maximum Average Forward Current Vs. Allowable Lead Temperature

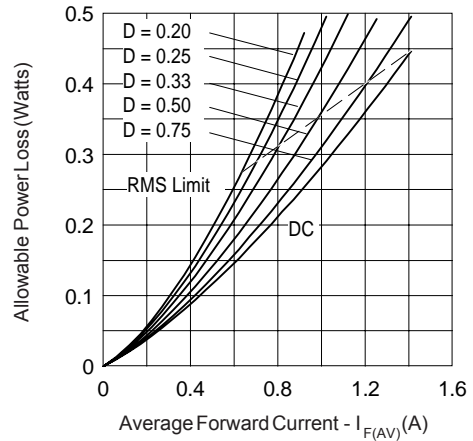


Fig. 5 - Maximum Average Forward Dissipation Vs. Average Forward Current

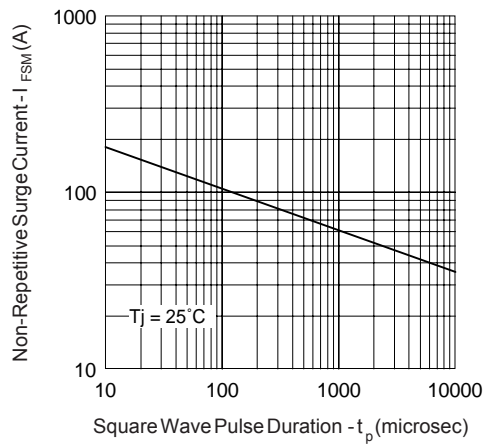


Fig. 6 - Maximum Peak Surge Forward Current Vs. Pulse Duration

- (2) Formula used: $T_c = T_j - (Pd + Pd_{REV}) \times R_{thJC}$;
 $Pd = \text{Forward Power Loss} = I_{F(AV)} \times V_{FM} @ (I_{F(AV)} / D)$ (see Fig. 6);
 $Pd_{REV} = \text{Inverse Power Loss} = V_{R1} \times I_R (1 - D)$

Ordering Information Table

Device Code	1N5817	TR
	①	②
1	-	Part Number:1A, 20V
2	-	TR= Tape & Reel package (5000 pcs)
	-	= Box package (1000 pcs)

Data and specifications subject to change without notice.
This product has been designed for Industrial Level and Lead-Free.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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